THR60U06SE



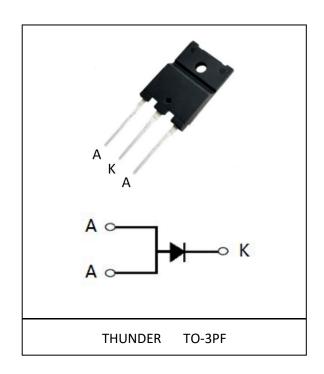
Thunder High Power Products

FRED Ultrafast Soft Recovery Diode, 60A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary			
VR 600 V			
lf(AV)	60A		
trr	30ns		



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	60	
Single pulse forward current	IFSM	Tc =25°C	600	А
Maximum repetitive forward current	İfrm	Square wave, 20kHZ	120	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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Electrical characteristics (Ta=25°C unless otherwise specified)

arameter	Symbol	Test Conditions	Min	Тур.	Max.	Units	
Breakdown voltage Blocking voltage	VBR, V _R	Ir=100µA	600				
Forward voltage	e VF	IF=60A		1.45	1.80	V	
		IF=60A, Tj =125°C		1.30	1.70		
Reverse leakage current	lr	VR= VRRM			50	μΑ	
		Tj=150°C, V _R =600V			500		
Reverse recovery	' trr —	I _F =0.5A, I _R =1A, I _{RR} =0.25A		50	70		
time		I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		32	45	ns	
Reverse recovery time	trr	$I_F = 60A, V_R = 300V,$ $d_{IF}/dt = -200A/\mu s, T_J = 25^{\circ}C$		55		ns	
Maximum Reverse Recovery Current	IRM			5		А	
Reverse Recovery Charge	Qrr			346		nC	
Reverse recovery time	trr	I_F =60A,VR =300V, d_{IF}/dt = -200A/ μ s ,T $_J$ =125 $^{\circ}$ C		132		ns	
Maximum Reverse Recovery Current	IRM			12		А	
Reverse Recovery Charge	Qrr			1960		nC	

Thermal characteristics

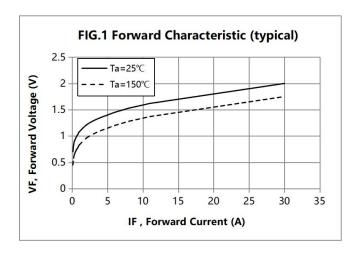
Paramter	Symbol	Тур	Units
Junction-to-Case	$R_{ heta ext{IC}}$	0.8	°C/W

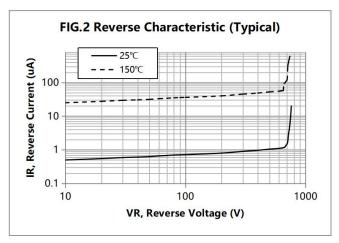
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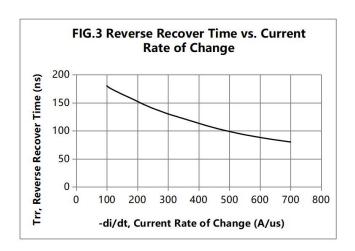


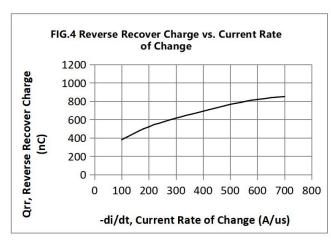


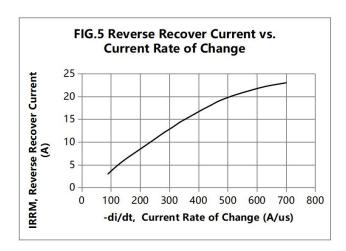
Electrical performance (typical)

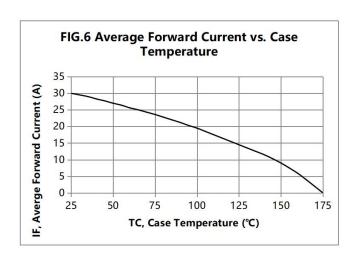












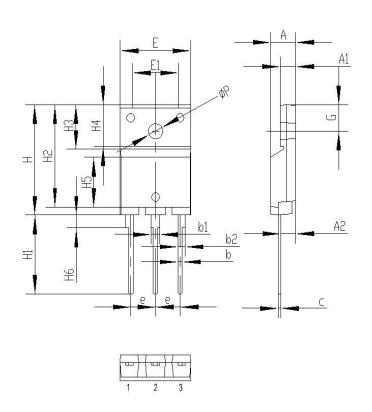
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Package Information

TO-3PF PACKAGE



Cumbal	Unit mm			
Symbol	Min	Тур	Max	
А	5.30	5.50	5.70	
A1	3.30	3.50	3.70	
A2	3.20	3.40	3.60	
b	0.80	1.0	1.20	
b1	1.80	2.00	2.20	
b2	1.40	1.60	1.80	
С	0.40	0.50	0.60	
е	5.25	5.45	5.65	
E	15.4	15.6	15.8	
E1	10.0	10.2	10.4	
Н	22.8	23.0	23.2	
H1	16.0	16.5	17.0	
H2	21.2	21.4	21.6	
Н3	9.10	9.30	9.50	
Н4	8.55	8.75	8.95	
Н5	10.2	10.4	10.6	
Н6	2.55	2.70	2.85	
G	5.3	5.5	5.7	
ФР	3.00	3.20	3.40	

Notice

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